



Substitute Form PTO-1449 (Modified)  <b>Information Disclosure Statement by Applicant</b> (Use several sheets if necessary)  (37 CFR §1.98(b))	U.S. Department of Commerce Patent and Trademark Office	Attorney's Docket No. <b>12732-034001</b>	Application No. <b>09/842,797</b>
	Applicant <b>Koichiro Tanaka</b>		
	Filing Date <b>April 27, 2001</b>	Group Art Unit <b>2822</b>	

U.S. Patent Documents							
Examiner Initial	Desig. ID	Document Number	Publication Date	Patentee	Class	Subclass	Filing Date If Appropriate
<b>MG</b>	AA	4,439,245	03/27/1984	WU			01/25/1982
	AB						
	AC						
	AD						
	AE						
	AF						
	AG						
	AH						
	AI						
	AJ						
	AK						

Foreign Patent Documents or Published Foreign Patent Applications								
Examiner Initial	Desig. ID	Document Number	Publication Date	Country or Patent Office	Class	Subclass	Translation	
							Yes	No
	AL							
	AM							
	AN							
	AO							
	AP							

Other Documents (include Author, Title, Date, and Place of Publication)		
Examiner Initial	Desig. ID	Document
<b>MG</b>	AQ	Hayashi et al., "FABRICATION OF LOW-TEMPERATURE BOTTOM-GATE POLY-SI TFTS ON LARGE-AREA SUBSTRATE BY LINEAR-BEAM EXCIMER LASER CRYSTALLIZATION AND ION DOPING METHOD," IEDM '95; Technical Digest of International Electron Devices Meeting, 33.3.1 - 33.3.4, pp. 829-832, December 10-13, 1995.
	AR	
	AS	
	AT	

Examiner Signature <i>Maria Guerrero</i>	Date Considered <b>6-2-05</b>
EXAMINER: Initials citation considered. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.	